NSN 5962-01-382-1248

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J	perating	remp	urature	Kange:

-65.0/+135.0 degrees celsius

Inclosure Configuration:

Dual-in-line

Voltage Rating And Type Per Characteristic:

4.5 volts applied and 5.5 volts applied

Memory Device Type:

First-in first-out

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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